# P-Channel 40-V (D-S) MOSFET

## **Key Features:**

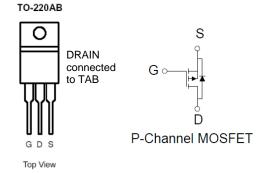
- Low r<sub>DS(on)</sub> trench technology
- · Low thermal impedance
- · Fast switching speed

# **Typical Applications:**

- Power Routing
- High Side Switch
- Motor Drives

PRODUCT SUMMARY			
V <sub>DS</sub> (V)	$r_{DS(on)}(m\Omega)$	I⊳(A)	
-40	$7.6 @ V_{GS} = -10V$	-90 <sup>a</sup>	
	9 @ V <sub>GS</sub> = -4.5V	-90"	





ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^{\circ}$ C UNLESS OTHERWISE NOTED)						
Parameter		Symbol	Limit	Units		
Drain-Source Voltage		$V_{DS}$	-40	V		
Gate-Source Voltage		$V_{GS}$	±20	[		
Continuous Drain Current a	T <sub>C</sub> =25°C	$I_D$	-90	Α		
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	-390	^		
Continuous Source Current (Diode Conduction) a T <sub>C</sub> =25°C		I <sub>S</sub>	-110	Α		
Power Dissipation	T <sub>C</sub> =25°C	$P_{D}$	300	W		
Operating Junction and Storage Temperature Range		$T_J, T_{stg}$	-55 to 175	°C		

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Maximum	Units		
Maximum Junction-to-Ambient	$R_{\theta JA}$	62.5	°C/W		
Maximum Junction-to-Case	$R_{\theta JC}$	0.5	C/VV		

1

#### Notes

- a. Package limited
- b. Pulse width limited by maximum junction temperature

### **Electrical Characteristics**

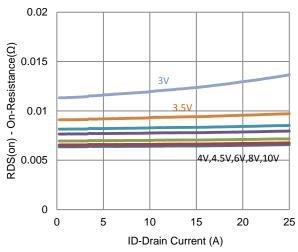
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static						
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = -250 \text{ uA}$	-1			V
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA
Zero Gate Voltage Drain Current		$V_{DS} = -32 \text{ V}, V_{GS} = 0 \text{ V}$			-1	uA
	I <sub>DSS</sub>	$V_{DS} = -32 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			-25	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} = -5 \text{ V}, V_{GS} = -10 \text{ V}$	-110			Α
Drain-Source On-Resistance <sup>a</sup>	r	$V_{GS} = -10 \text{ V}, I_D = -50 \text{ A}$			7.6	mΩ
	r <sub>DS(on)</sub>	$V_{GS} = -4.5 \text{ V}, I_{D} = -44 \text{ A}$			9	
Forward Transconductance a	g <sub>fs</sub>	$V_{DS} = -15 \text{ V}, I_{D} = -20 \text{ A}$		29		S
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	$I_{S} = -55 \text{ A}, V_{GS} = 0 \text{ V}$		-0.95		V
Dynamic <sup>b</sup>						
Total Gate Charge	$Q_g$	$V_{DS} = -20 \text{ V}, V_{GS} = -4.5 \text{ V},$ $I_{D} = -20 \text{ A}$		122		nC
Gate-Source Charge	$Q_gs$			32		
Gate-Drain Charge	$Q_{gd}$			50		
Turn-On Delay Time	t <sub>d(on)</sub>	$V_{DS}$ = -20 V, $R_{L}$ = 1 Ω, $I_{D}$ = -20 A, $V_{GEN}$ = -10 V, $R_{GEN}$ = 6 Ω		17		ns
Rise Time	t <sub>r</sub>			28		
Turn-Off Delay Time	$t_{d(off)}$			284		
Fall Time	t <sub>f</sub>			115		
Input Capacitance	C <sub>iss</sub>	$V_{DS} = -15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ Mhz}$		9763		pF
Output Capacitance	C <sub>oss</sub>			871		
Reverse Transfer Capacitance	$C_{rss}$			716		

#### Notes

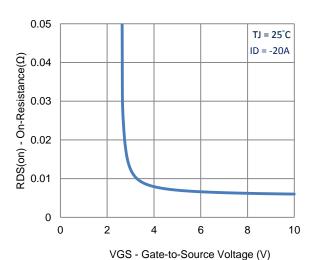
- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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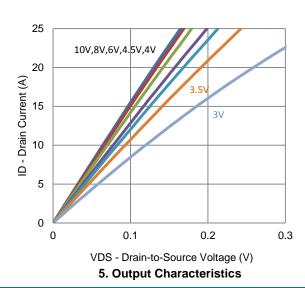
## **Typical Electrical Characteristics**

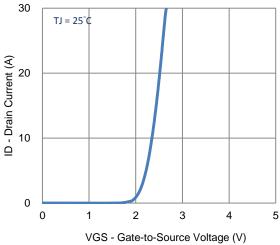


#### 1. On-Resistance vs. Drain Current

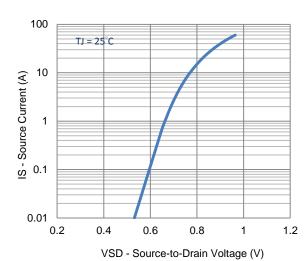


3. On-Resistance vs. Gate-to-Source Voltage

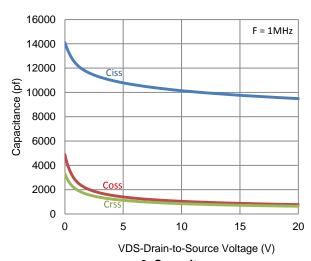




2. Transfer Characteristics

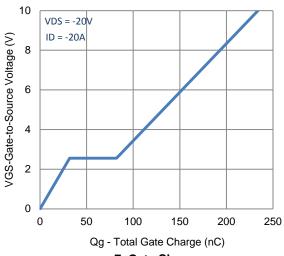


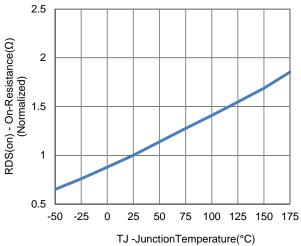
4. Drain-to-Source Forward Voltage



6. Capacitance

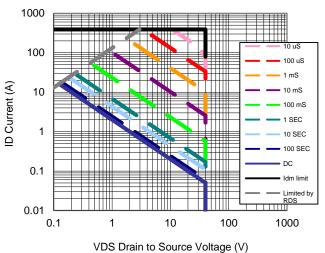
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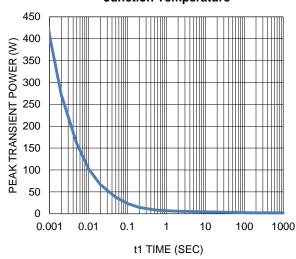




7. Gate Charge

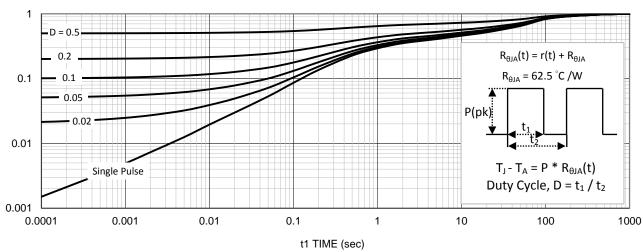






9. Safe Operating Area

10. Single Pulse Maximum Power Dissipation



11. Normalized Thermal Transient Junction to Ambient

# **Package Information**

